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ON Semiconductor®

FDD9411-F085

N-Channel PowerTrench[®] MOSFET 40 V, 25 A, 7.8 m Ω

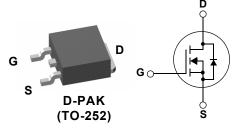
Features

- Typical $R_{DS(on)}$ = 6.2 m Ω at V_{GS} = 10V, I_D = 15 A
- Typical $Q_{g(tot)}$ = 15 nC at V_{GS} = 10V, I_D = 15 A
- UIS Capability
- RoHS Compliant
- Qualified to AEC Q101

Applications

- Automotive Engine Control
- PowerTrain Management
- Solenoid and Motor Drivers
- Electronic Steering
- Integrated Starter/Alternator
- Primary Switch for 12V Systems





MOSFET Maximum Ratings $T_J = 25$ °C unless otherwise noted.

Symbol	Parameter		Ratings	Units
V_{DSS}	Drain-to-Source Voltage		40	V
V_{GS}	Gate-to-Source Voltage		±20	V
ı	Drain Current - Continuous (V_{GS} =10) (Note 1) T_C = 25°C		25	Α
I _D	Pulsed Drain Current	T _C = 25°C	See Figure 4	_ ^
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	43.2	mJ
D	Power Dissipation		48.4	W
P_{D}	Derate Above 25°C		0.32	W/°C
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case		3.1	°C/W
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	52	°C/W

Notes

- 1: Current is limited by bondwire configuration.
- 2: Starting T_J = 25°C, L = 0.6mH, I_{AS} = 12A, V_{DD} = 40V during inductor charging and V_{DD} = 0V during time in avalanche.

 3: R_{0,JA} is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder
- 3: R_{0,JA} is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{0,JC} is guaranteed by design, while R_{0,JA} is determined by the board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDD9411	FDD9411-F085	D-PAK(TO-252)	13"	16mm	2500units

Units

Max.

Тур.

Electrical Characteristics	$T_J = 25$ °C unless otherwise noted.
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Parameter

Off Cna	aracteristics					
B _{VDSS}	Drain-to-Source Breakdown Voltage	$I_D = 250 \mu A, V_{GS} = 0 V$	40	-	-	V
	Drain-to-Source Leakage Current	V_{DS} =40V, T_{J} = 25°C	-	-	1	μА
IDSS		$V_{GS} = 0V$ $T_J = 175^{\circ}C \text{ (Note 4)}$	-	-	1	mA
I _{GSS}	Gate-to-Source Leakage Current	V _{GS} = ±20V	-	-	±100	nA

Test Conditions

Min.

On Characteristics

Symbol

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu A$		2.0	3.4	4.0	V
R _{DS(on)}	Drain to Source On Resistance	I _D = 15A,	$T_J = 25^{\circ}C$		6.2	7.8	mΩ
		V _{GS} = 10V	T _J = 175°C (Note 4)	-	11.2	14	mΩ

Dynamic Characteristics

C _{iss}	Input Capacitance	V _{DS} = 25V, V _{GS} = 0V, f = 1MHz		-	1080	-	pF
C _{oss}	Output Capacitance			-	340	-	pF
C _{rss}	Reverse Transfer Capacitance	1 - 1101112	-1 - 11VIDZ		22	-	pF
R_g	Gate Resistance	f = 1MHz		-	2.6	-	Ω
$Q_{g(ToT)}$	Total Gate Charge	V _{GS} = 0 to 10V	V _{DD} = 32V	-	15	22.5	nC
$Q_{g(th)}$	Threshold Gate Charge	$V_{GS} = 0$ to 2V	I _D = 15A	-	2	-	nC
Q _{gs}	Gate-to-Source Gate Charge		_	-	5.3	-	nC
Q_{gd}	Gate-to-Drain "Miller" Charge			-	2.8	-	nC

Switching Characteristics

t_{on}	Turn-On Time		-	-	24	ns
t _{d(on)}	Turn-On Delay		-	8.7	-	ns
t _r	Rise Time	V _{DD} = 20V, I _D = 15A,	-	7.2	-	ns
t _{d(off)}	Turn-Off Delay	V_{GS} = 10V, R_{GEN} = 6Ω	-	15.8	-	ns
t _f	Fall Time		-	4.4	-	ns
t _{off}	Turn-Off Time		-	-	30	ns

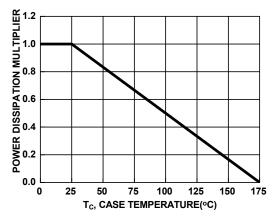
Drain-Source Diode Characteristics

V _{SD} Source-to-Drain Diode Voltage	Source to Drain Diode Voltage	I _{SD} = 15A, V _{GS} = 0V	-	-	1.25	V
	$I_{SD} = 7.5A, V_{GS} = 0V$	-	-	1.2	٧	
t _{rr}	Reverse-Recovery Time	V _{DD} = 32V, I _F = 15A,	-	35	53	ns
Q _{rr}	Reverse-Recovery Charge	$dI_{SD}/dt = 100A/\mu s$	-	20	30	nC

Note:

4: The maximum value is specified by design at T_J = 175°C. Product is not tested to this condition in production.

Typical Characteristics



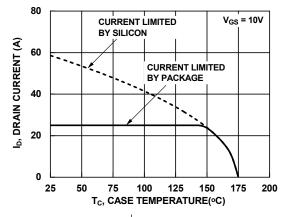


Figure 1. Normalized Power Dissipation vs. Case Temperature

Figure 2. Maximum Continuous Drain Current vs.
Case Temperature

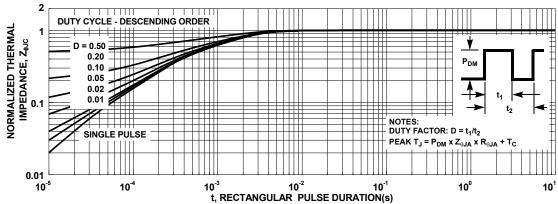


Figure 3. Normalized Maximum Transient Thermal Impedance

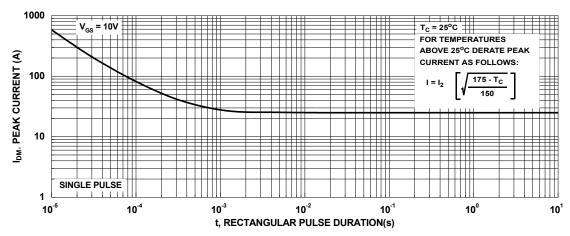


Figure 4. Peak Current Capability

Typical Characteristics

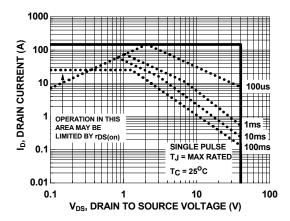
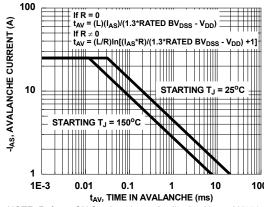


Figure 5. Forward Bias Safe Operating Area



NOTE: Refer to ON Semiconductor Application Notes AN7514 and AN7515

Figure 6. Unclamped Inductive Switching Capability

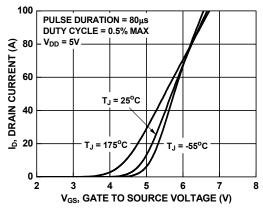


Figure 7. Transfer Characteristics

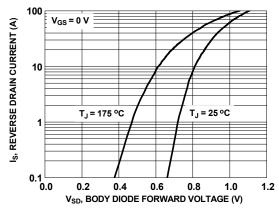


Figure 8. Forward Diode Characteristics

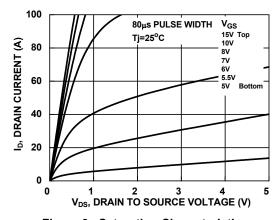


Figure 9. Saturation Characteristics

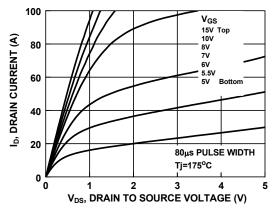


Figure 10. Saturation Characteristics

Typical Characteristics

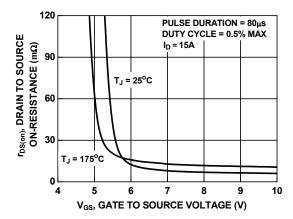


Figure 11. R_{DSON} vs. Gate Voltage

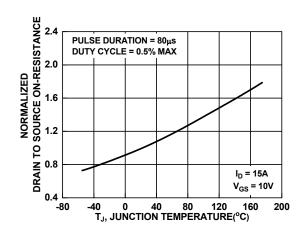


Figure 12. Normalized R_{DSON} vs. Junction Temperature

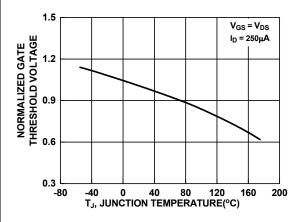


Figure 13. Normalized Gate Threshold Voltage vs. Temperature

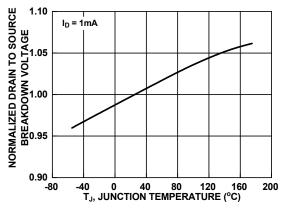


Figure 14. Normalized Drain to Source Breakdown Voltage vs. Junction Temperature

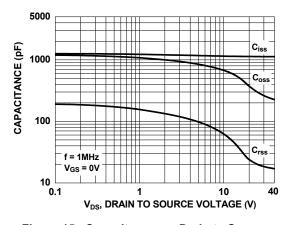


Figure 15. Capacitance vs. Drain to Source Voltage

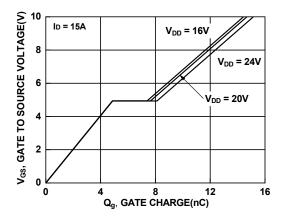


Figure 16. Gate Charge vs. Gate to Source Voltage

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